MSKSEMI 美森科













ESD

TVS

TSS

MOV

GDT

PLED



Product specification





Features

- 56Watts peak pulse power (tp =
- 8/20µs)
- Tiny DFN1006 package
- Solid-state silicon-avalanche technology
- Low clamping voltage
- Low leakage current
- Low capacitance (Cj=0.45pF typ.)
- Protection one data/power line to: IEC 61000-4-2 ±20kV contact ±20kV air IEC 61000-4-4 (EFT) 40A (5/50ns)
 IEC 61000-4-5 (Lightning) 4A (8/20µs)

Applications

- Cell Phone Handsets and Accessories
- Microprocessor based equipment
- Personal Digital Assistants (PDA's)
- Notebooks, Desktops, and Servers
- Portable Instrumentation

Mechanical Data

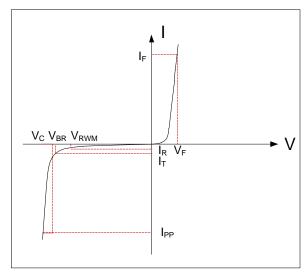
- Molding compound flammability rating: UL 94V-0
- Packaging: Tape and Reel
- RoHS/WEEE Compliant

Reference News

PACKAGE OUTLINE	Circuit Diagram	Marking
DFN1006-2		7X

Electrical Parameters (TA = 25°C unless otherwise noted)

Symbol	Parameter		
Ipp	Maximum Reverse Peak Pulse Current		
Vc	Clamping Voltage @ IPP		
Vrwm	Working Peak Reverse Voltage		
Ir	Maximum Reverse Leakage Current @ VRWM		
VBR	Breakdown Voltage @ IT		
Іт	Test Current		





Absolute Maximum Rating

Rating	Symbol	Value	Units
Peak Pulse Power ($t_p = 8/20 \mu s$)	P _{PP}	56	Watts
Peak Pulse Current ($t_p = 8/20 \mu s$) (note1)	I _{pp}	4	А
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	Vesd	20 20	kV
Lead Soldering Temperature	TL	260(10seconds)	°C
Junction Temperature	TJ	-55 to + 125	°C
Storage Temperature	T _{stg}	-55 to + 125	°C

Electrical Characteristics

Parameter	Symbol	Conditions	Min	Typical	Max	Units
Reverse Stand-Off Voltage	V _{RWM}				5.0	V
Reverse Breakdown Voltage	V_{BR}	l⊤=1mA	6.0	7.5		V
Reverse Leakage Current	I _R	V_{RWM}=5V,Т=25 ℃			100	nA
Peak Pulse Current	I _{PP}	tp =8/20µs			4	А
Clamping Voltage	Vc	I _{PP} =4A,t _p =8/20μs			14	V
Junction Capacitance	Cj	$V_R = 0V$, f = 1MHz		0.45	0.6	pF



TypicalCharacteristics

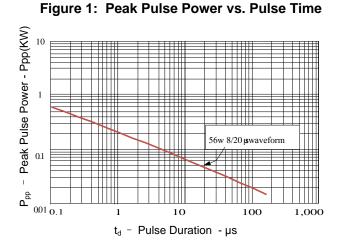


Figure 2: Power Derating Curve

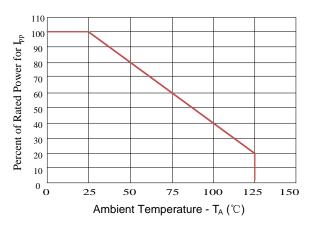
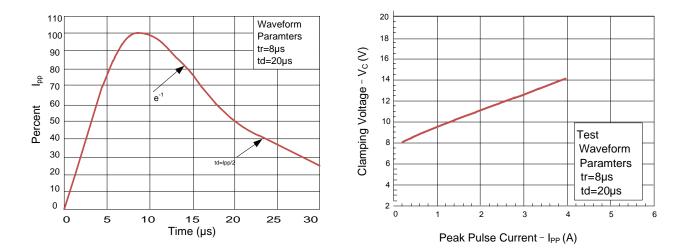


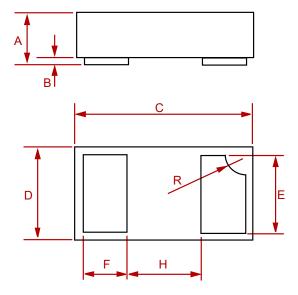
Figure3: Pulse Waveform

Figure 4: Clamping Voltage vs.lpp



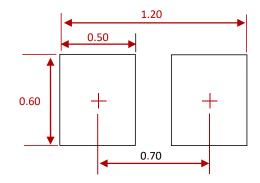


PACKAGE MECHANICAL DATA



Dim	Inches		Millimeters		
Dim	MIN	MAX	MIN	МАХ	
А	0.0125	0.02	0.32	0.52	
В	0.000	0.002	0.00	0.05	
С	0.037	0.043	0.95	1.080	
D	0.022	0.027	0.55	0.680	
E	0.016	0.024	0.40	0.60	
F	0.008	0.012	0.20	0.30	
н	0.015Typ.		0.40	Тур.	
R	0.001	0.005	0.05	0.15	

Suggested Pad Layout



NOTES:

- 1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).
- 2. THIS LAND PATTERN IS FOR REFERENCE PURPOSES ONLY.
 - CONSULT YOUR MANUFACTURING GROUP TO ENSURE YOUR COMPANY'S MANUFACTURING GUIDELINES ARE MET.

REEL SPECIFICATION

P/N	PKG	QTY
ESD5341N-MS	DFN1006-2	10000



ESD5341N-MS

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